

## Features

- RoHS compliant\*
- Protects up to four I/O ports
- Surge protection
- ESD protection
- Low capacitance: 6 pF

## Applications

- Ethernet - 10/100 Base T
- Personal digital assistants
- LAN devices
- Instrumentation

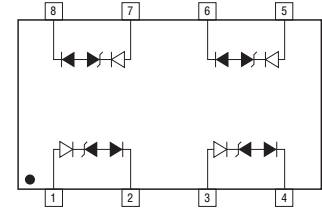
# CDNBS08-SLVU2.8-4 - Low Capacitance TVS Array

## General Information

The markets of portable communications, computing and video equipment are challenging the semiconductor industry to develop increasingly smaller electronic components.

Bourns offers Transient Voltage Suppressor Array combination diodes for surge and ESD protection applications in an eight lead narrow body SOIC package size format. Bourns® Chip Diodes conform to JEDEC standards, are easy to handle on standard pick and place equipment and their flat configuration minimizes roll away.

The Bourns® device will meet IEC 61000-4-2 (ESD), IEC 61000-4-4 (EFT) and IEC 61000-4-5 (Surge) requirements.



## Electrical Characteristics (@ T<sub>A</sub> = 25 °C Unless Otherwise Noted)

Parameter	Symbol	Min.	Nom.	Max.	Unit
Peak Pulse Current (t <sub>p</sub> = 8/20 μs)	I <sub>PP</sub>			30	A
Peak Pulse Power (t <sub>p</sub> = 8/20 μs) <sup>1</sup>	P <sub>PP</sub>			600	W
Working Voltage	V <sub>WM</sub>			2.8	V
Breakdown Voltage @ 1 mA	V <sub>BR</sub>	3.0			V
Leakage Current @ V <sub>WM</sub>	I <sub>D</sub>		0.1	1.0	μA
Capacitance @ 0 V, 1 MHz	C		6		pF
Snapback Voltage @ 50 mA		2.8			V
ESD Protection per IEC 61000-4-2 Contact Discharge Air Discharge	ESD	± 8 ± 15		± 30 ± 30	kV
EFT Protection per IEC 61000-4-4 @ 5/50 ns	EFT			60	A
Surge Protection per IEC 61000-4-5 Clamping Voltage @ 8/20 μs	@ I <sub>p</sub> = 5 A <sup>2</sup>			10	V
	@ I <sub>p</sub> = 24 A <sup>2</sup>		13	15	V
	@ I <sub>PP</sub> = 30 A <sup>2</sup>		15	21	V

Notes:

1. See Peak Pulse Power vs. Pulse Time.
2. Each differential line pair.

## Thermal Characteristics (@ T<sub>A</sub> = 25 °C Unless Otherwise Noted)

Parameter	Symbol	Min.	Nom.	Max.	Unit
Junction Temperature Range	T <sub>J</sub>	-55	+25	+125	°C
Storage Temperature Range	T <sub>STG</sub>	-55	+25	+150	°C

\*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.

Specifications are subject to change without notice.

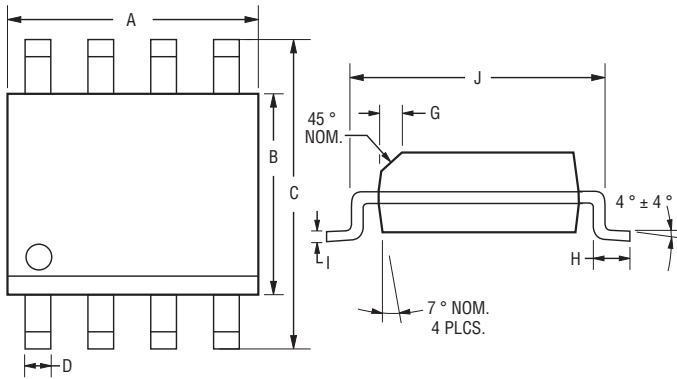
Customers should verify actual device performance in their specific applications.

# CDNBS08-SLVU2.8-4 - Low Capacitance TVS Array

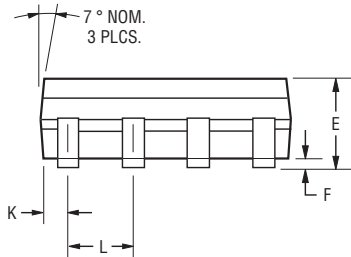


## Product Dimensions

This is an RoHS compliant molded JEDEC narrow body SO-8 package with 100 % Sn plating on the lead frame. It weighs approximately 15 mg and has a flammability rating of UL 94V-0.

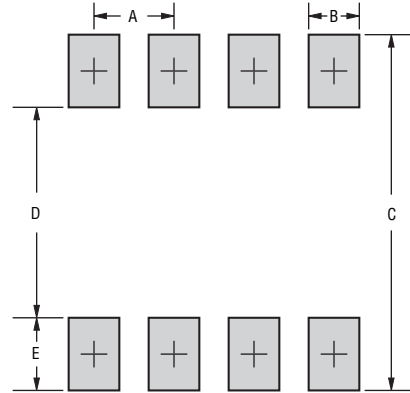


DIMENSIONS =  $\frac{\text{MILLIMETERS}}{\text{(INCHES)}}$



Dimensions	
A	$\frac{4.80 - 5.00}{(0.189 - 0.197)}$
B	$\frac{3.81 - 4.00}{(0.150 - 0.157)}$
C	$\frac{5.80 - 6.20}{(0.228 \pm 0.244)}$
D	$\frac{0.36 - 0.51}{(0.014 - 0.020)}$
E	$\frac{1.35 - 1.75}{(0.053 - 0.069)}$
F	$\frac{0.102 - 0.203}{(0.004 - 0.008)}$
G	$\frac{0.25 - 0.50}{(0.010 - 0.020)}$
H	$\frac{0.51 - 1.12}{(0.020 - 0.044)}$
I	$\frac{0.190 - 0.229}{(0.0075 - 0.0090)}$
J	$\frac{4.60 - 5.21}{(0.181 - 0.205)}$
K	$\frac{0.28 - 0.79}{(0.011 - 0.031)}$
L	$\frac{1.27}{(0.050)}$

## Recommended Footprint

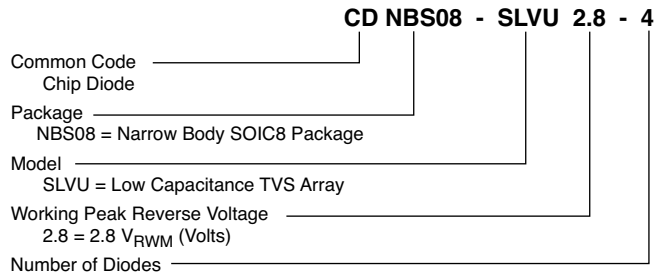


Dimensions	
A	$\frac{1.143 - 1.397}{(0.045 - 0.065)}$
B	$\frac{0.635 - 0.889}{(0.025 - 0.035)}$
C	$\frac{6.223}{(0.245)}$ Min.
D	$\frac{3.937 - 4.191}{(0.155 - 0.165)}$
E	$\frac{1.016 - 1.27}{(0.040 - 0.050)}$

## Typical Part Marking

CDNBS08-SLVU2.8-4 ..... **B** SL4

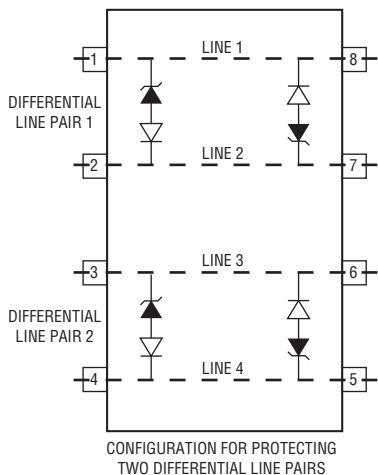
## How to Order



Specifications are subject to change without notice.  
 Customers should verify actual device performance in their specific applications.

# CDNBS08-SLVU2.8-4 - Low Capacitance TVS Array

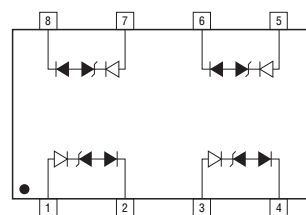
## Application Diagram



## Device Pinout

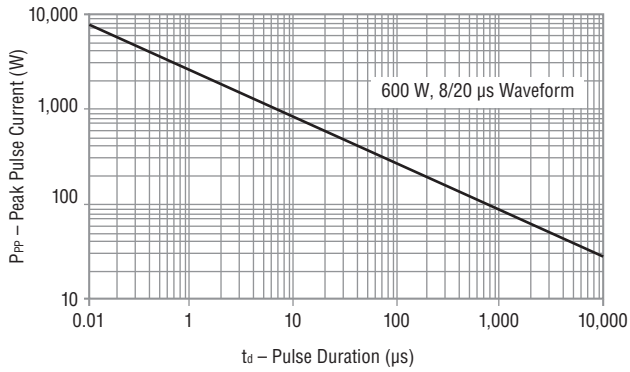
Pin	Unidirectional Common Mode	Bidirectional Common Mode	Bidirectional Differential Mode
1	Line 1	Line 1	Line Pair 1
2	GND	GND	Line Pair 1
3	Line 3	GND	Line Pair 2
4	GND	Line 2	Line Pair 2
5	Line 4	Line 2	Line Pair 2
6	GND	GND	Line Pair 2
7	Line 2	GND	Line Pair 1
8	GND	Line 1	Line Pair 1

## Block Diagram

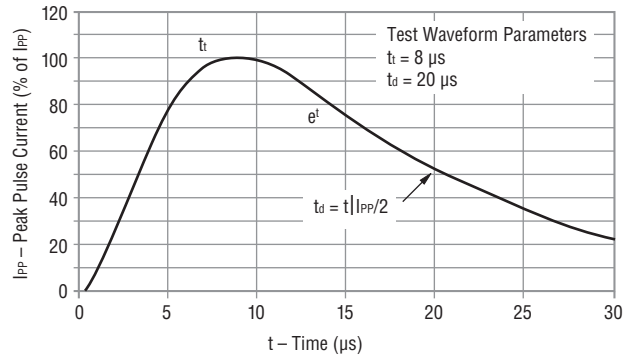


**Performance Graphs**

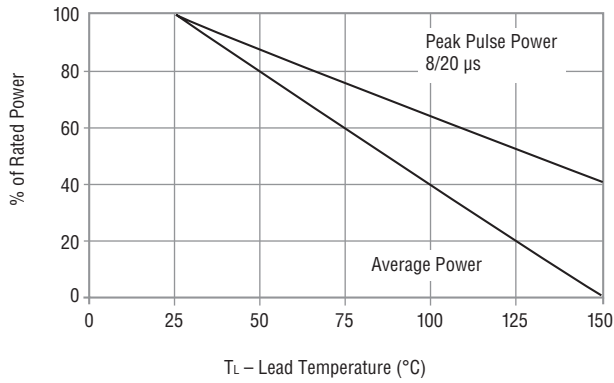
**Peak Pulse Power vs Pulse Time**



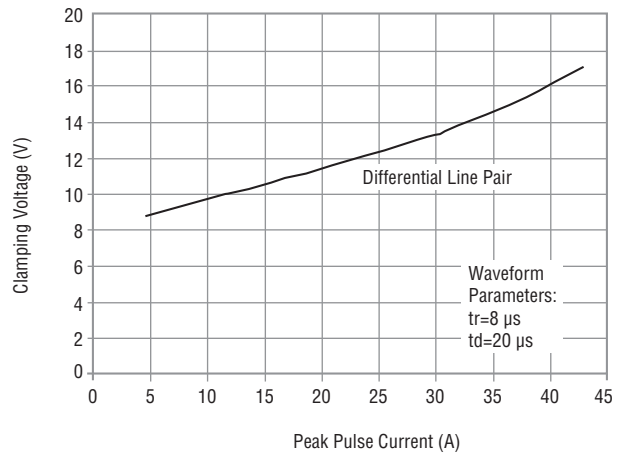
**Pulse Waveform**



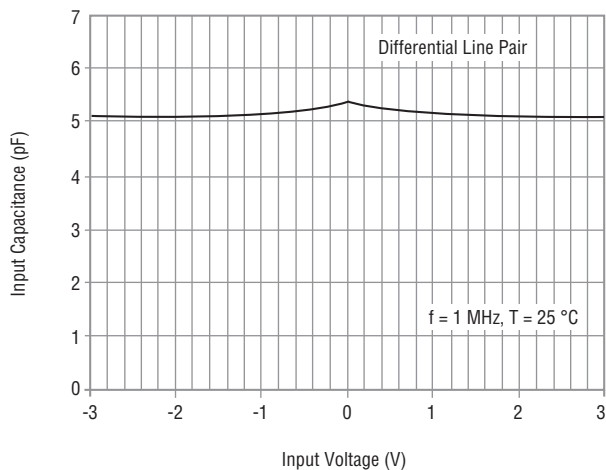
**Power Derating Curve**



**Clamping Voltage vs. Peak Pulse Current**



**Variation of  $C_{in}$  vs.  $V_{in}$**

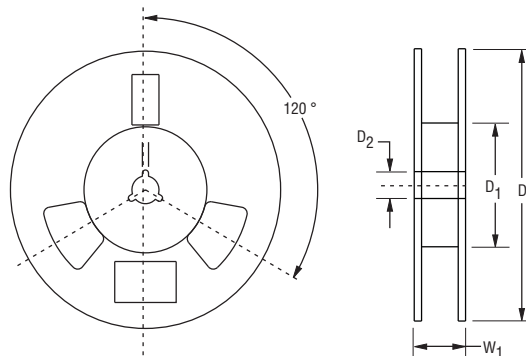
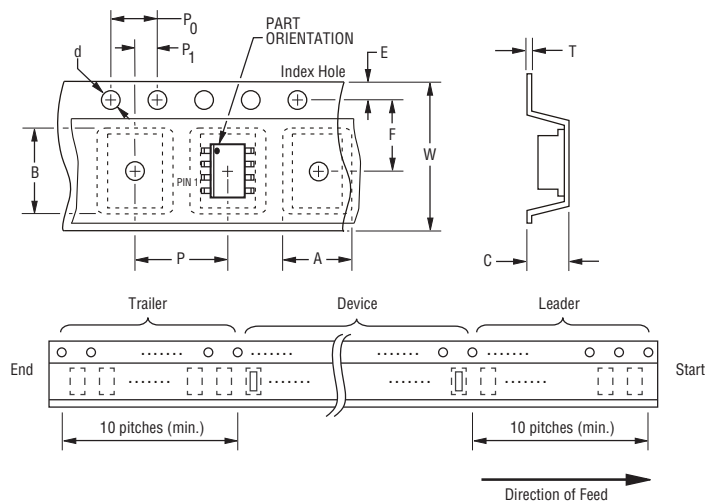


# CDNBS08-SLVU2.8-4 - Low Capacitance TVS Array

**BOURNS®**

## Packaging Information

The product is packaged in tape and reel format per EIA-481 standard.



DIMENSIONS:  $\frac{\text{MM}}{\text{(INCHES)}}$

Item	Symbol	NSOIC 8L
Carrier Width	A	$\frac{6.7 \pm 0.10}{(0.264 \pm 0.004)}$
Carrier Length	B	$\frac{5.5 \pm 0.10}{(0.217 \pm 0.004)}$
Carrier Depth	C	$\frac{2.10 \pm 0.10}{(0.083 \pm 0.004)}$
Sprocket Hole	d	$\frac{1.55 \pm 0.05}{(0.061 \pm 0.002)}$
Reel Outside Diameter	D	$\frac{330}{(12.992)}$
Reel Inner Diameter	D <sub>1</sub>	$\frac{80.0}{(3.1500)}$ MIN.
Feed Hole Diameter	D <sub>2</sub>	$\frac{13.0 \pm 0.20}{(0.512 \pm 0.008)}$
Sprocket Hole Position	E	$\frac{1.75 \pm 0.10}{(0.069 \pm 0.004)}$
Punch Hole Position	F	$\frac{3.50 \pm 0.05}{(0.138 \pm 0.002)}$
Punch Hole Pitch	P	$\frac{8.00 \pm 0.10}{(0.315 \pm 0.004)}$
Sprocket Hole Pitch	P <sub>0</sub>	$\frac{4.00 \pm 0.10}{(0.157 \pm 0.004)}$
Embossment Center	P <sub>1</sub>	$\frac{2.00 \pm 0.05}{(0.079 \pm 0.002)}$
Overall Tape Thickness	T	$\frac{0.20 \pm 0.10}{(0.008 \pm 0.004)}$
Tape Width	W	$\frac{12.00 \pm 0.20}{(0.472 \pm 0.008)}$
Reel Width	W <sub>1</sub>	$\frac{18.4}{(0.724)}$ MAX.
Quantity per Reel	--	2500

REV. 12/12

Specifications are subject to change without notice.

Customers should verify actual device performance in their specific applications.

**BOURNS®**

### Asia-Pacific:

Tel: +886-2 2562-4117

Fax: +886-2 2562-4116

### Europe:

Tel: +41-41 768 5555

Fax: +41-41 768 5510

### The Americas:

Tel: +1-951 781-5500

Fax: +1-951 781-5700

[www.bourns.com](http://www.bourns.com)

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Bourns:

[CDNBS08-SLVU2.8-4](#)